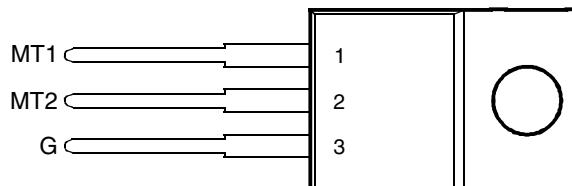


- High Current Triacs
- 16 A RMS
- Glass Passivated Wafer
- 400 V to 800 V Off-State Voltage
- 125 A Peak Current
- Max I_{GT} of 50 mA (Quadrants 1 - 3)

TO-220 PACKAGE
(TOP VIEW)

Pin 2 is in electrical contact with the mounting base.

MDC2ACA

absolute maximum ratings over operating case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Repetitive peak off-state voltage (see Note 1)	V_{DRM}	400 600 700 800	V
Full-cycle RMS on-state current at (or below) 70°C case temperature (see Note 2)	$I_{T(RMS)}$	16	A
Peak on-state surge current full-sine-wave at (or below) 25°C case temperature (see Note 3)	I_{TSM}	125	A
Peak gate current	I_{GM}	± 1	A
Operating case temperature range	T_C	-40 to +110	°C
Storage temperature range	T_{stg}	-40 to +125	°C
Lead temperature 1.6 mm from case for 10 seconds	T_L	230	°C

- NOTES: 1. These values apply bidirectionally for any value of resistance between the gate and Main Terminal 1.
 2. This value applies for 50-Hz full-sine-wave operation with resistive load. Above 70°C derate linearly to 110°C case temperature at the rate of 400 mA/°C.
 3. This value applies for one 50-Hz full-sine-wave when the device is operating at (or below) the rated value of peak reverse voltage and on-state current. Surge may be repeated after the device has returned to original thermal equilibrium.

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
I_{DRM} Repetitive peak off-state current	V_D = rated V_{DRM}	I_G = 0	T_C = 110°C			± 2	mA
I_{GT} Gate trigger current	$V_{supply} = +12\text{ V}\dagger$ $V_{supply} = +12\text{ V}\ddagger$ $V_{supply} = -12\text{ V}\dagger$ $V_{supply} = -12\text{ V}\ddagger$	$R_L = 10\ \Omega$ $R_L = 10\ \Omega$ $R_L = 10\ \Omega$ $R_L = 10\ \Omega$	$t_{p(g)} > 20\ \mu\text{s}$ $t_{p(g)} > 20\ \mu\text{s}$ $t_{p(g)} > 20\ \mu\text{s}$ $t_{p(g)} > 20\ \mu\text{s}$		12 -19 -16 34	50 -50 -50	mA
V_{GT} Gate trigger voltage	$V_{supply} = +12\text{ V}\dagger$ $V_{supply} = +12\text{ V}\ddagger$ $V_{supply} = -12\text{ V}\dagger$ $V_{supply} = -12\text{ V}\ddagger$	$R_L = 10\ \Omega$ $R_L = 10\ \Omega$ $R_L = 10\ \Omega$ $R_L = 10\ \Omega$	$t_{p(g)} > 20\ \mu\text{s}$ $t_{p(g)} > 20\ \mu\text{s}$ $t_{p(g)} > 20\ \mu\text{s}$ $t_{p(g)} > 20\ \mu\text{s}$		0.8 -0.8 -0.8 0.9	2 -2 -2 2	V
V_T On-state voltage	$I_{TM} = \pm 22.5\text{ A}$	$I_G = 50\text{ mA}$	(see Note 4)		± 1.4	± 1.7	V

† All voltages are with respect to Main Terminal 1.

NOTE 4: This parameter must be measured using pulse techniques, $t_p = \leq 1\text{ ms}$, duty cycle $\leq 2\%$. Voltage-sensing contacts separate from the current carrying contacts are located within 3.2 mm from the device body.**PRODUCT INFORMATION**

electrical characteristics at 25°C case temperature (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
I_H Holding current	$V_{\text{supply}} = +12 \text{ V} \dagger$ $V_{\text{supply}} = -12 \text{ V} \dagger$	$I_G = 0$	$\text{Init}' I_{TM} = 100 \text{ mA}$		22	40	mA
I_L Latching current	$V_{\text{supply}} = +12 \text{ V} \dagger$ $V_{\text{supply}} = -12 \text{ V} \dagger$	(see Note 5)	$I_G = 0$		-12	-40	mA
dv/dt Critical rate of rise of off-state voltage	$V_D = \text{Rated } V_D$	$I_G = 0$	$T_C = 110^\circ\text{C}$		± 400		$\text{V}/\mu\text{s}$
$dv/dt_{(c)}$ Critical rise of commutation voltage	$V_D = \text{Rated } V_D$		$T_C = 80^\circ\text{C}$	± 1.2	± 9		$\text{V}/\mu\text{s}$
di/dt Critical rate of rise of on-state current	$V_D = \text{Rated } V_D$ $di/dt = 0.5 I_{T(\text{RMS})}/\text{ms}$	$I_{GT} = 50 \text{ mA}$	$T_C = 110^\circ\text{C}$		± 100		$\text{A}/\mu\text{s}$

† All voltages are with respect to Main Terminal 1.

NOTE 5: The triacs are triggered by a 15-V (open-circuit amplitude) pulse supplied by a generator with the following characteristics:
 $R_G = 100 \Omega$, $t_{p(g)} = 20 \mu\text{s}$, $t_f \leq 15 \text{ ns}$, $f = 1 \text{ kHz}$.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1.9	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	$^\circ\text{C}/\text{W}$

TYPICAL CHARACTERISTICS

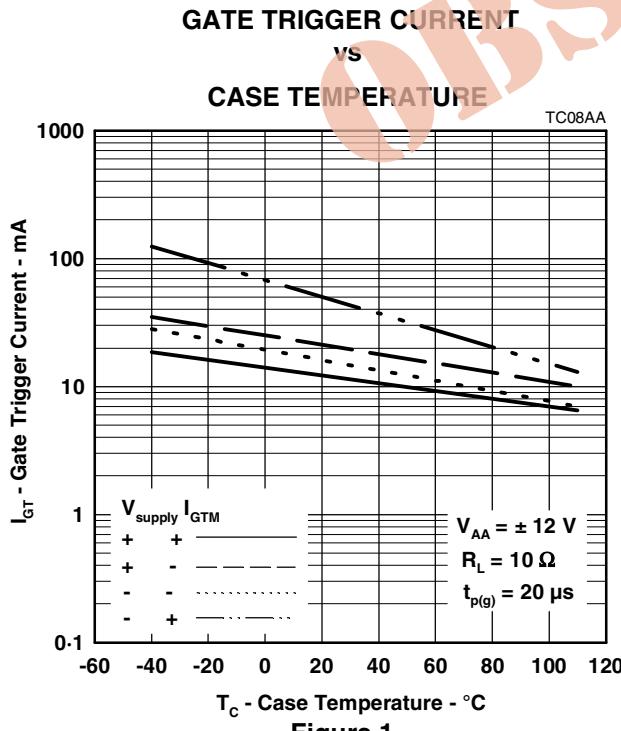


Figure 1.

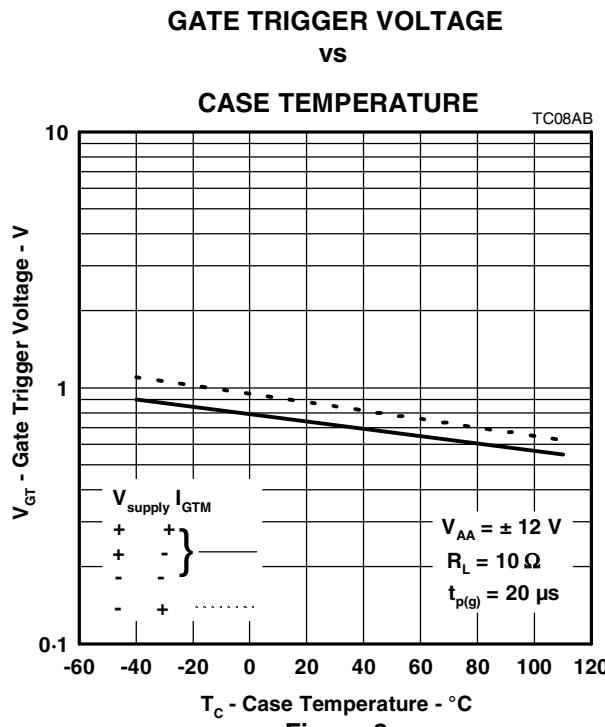


Figure 2.

PRODUCT INFORMATION

DECEMBER 1971 - REVISED SEPTEMBER 2002
 Specifications are subject to change without notice.

TYPICAL CHARACTERISTICS

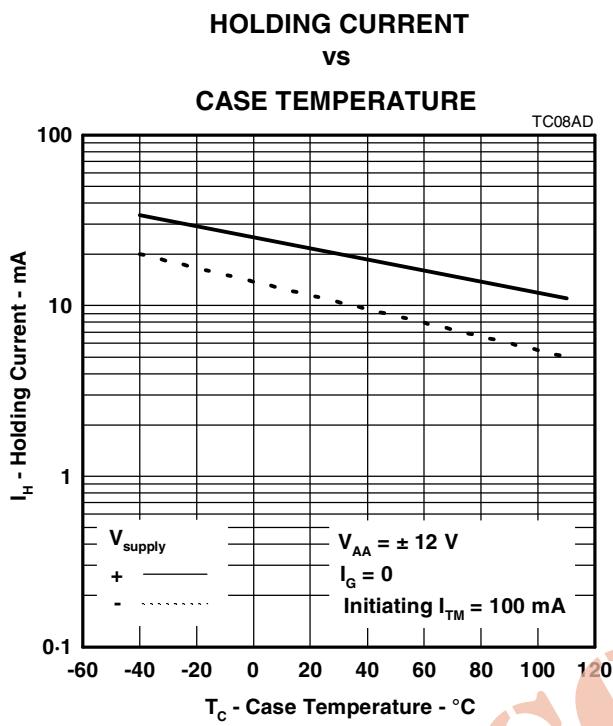


Figure 3.

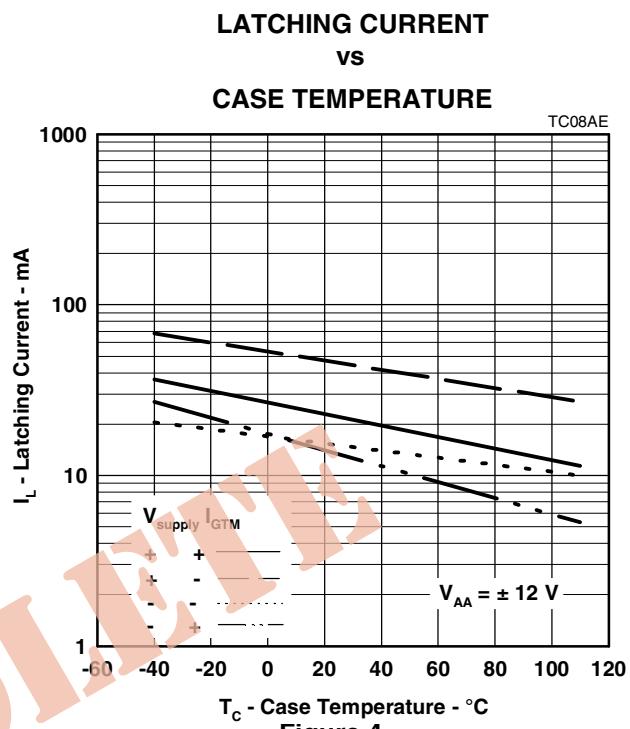


Figure 4.

PRODUCT INFORMATION

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